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Sensitivity Enhancement of CO₂ Sensors at Room Temperature Based on the CZO Nanorod Architecture

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Hall effect study. The gradual increase of the power applied on the target source significantly affected the morphology of the CZO thin film, which is reflected in the CO_2 -sensing performance. The best gas response to CO_2 was recorded for CZO-60 W with a response of 1.45 for 500 ppm $CO₂$, and the response/recovery times were 72 and 35 s, respectively. The distinguishing feature of the CZO sensor is its ability to effectively and rapidly detect the CO₂ target gas at room temperature (∼27 °C, RT).

KEYWORDS: *CO2 sensors, CZO nanorods, cobalt-doped ZnO, RF magnetron sputtering, room-temperature sensing, gas response, morphology control, thin film deposition*

In the last decades, many investigations have been devoted
to hazardous gas detection technology in order to sustain its
wide usere in various fields, such as healthcare, industrial wide usage in various fields, such as healthcare, industrial safety, and environmental monitoring.^{[1](#page-9-0)[,2](#page-10-0)} Within the functioning principles, different types of gas detection technology based on chemo-resistive, surface acoustic wave, optical, gas chromatography, and electrochemical sensors have been explored. $3,4$ Among these detectors, chemo-resistive-type gas sensors based on metal oxide semiconductors (MOS) were found to be the most preferable solution for future applications due to their outstanding electrochemical, physical, and gas-sensing properties.^{[5](#page-10-0)} The advantages such as lengthy lifespan, ecofriendliness, easy miniaturization, recyclability, low-cost enhancement of mass production, and environmental sustainability of the product. Moreover, the range of target gas being detected by the MOS-based sensor is wider than the other gas sensor types and is in the concentration range from ppb to ppt.⁶ For environmental monitoring of several important urban air pollutants, such as nitrogen oxides (NO_x) , ozone $(O₃)$, volatile organic compounds (VOCs), sulfur oxides (SO*x*), and carbon oxides (CO_x) , the operability of sensing materials, namely TiO_2 , In_2O_3 , SnO_2 , and ZnO, have demonstrated high potential for gas-sensing and monitoring applications.^{[7,8](#page-10-0)}

One of the promising MOS-based nanomaterials for gas detectors is the ZnO nanostructure, which is abundantly available in nature.^{[9](#page-10-0)} Besides, ZnO is widely used in sensing applications owing to its excellent optical and electrical characteristics, such as low intrinsic carrier concentration (<10⁶ cm⁻³), high maximum n-type doping (10¹⁹ cm⁻³), and its ability to achieve p-type doping $(<10^{-17} \text{ cm}^{-3})$ $(<10^{-17} \text{ cm}^{-3})$ $(<10^{-17} \text{ cm}^{-3})$.¹⁰ Moreover, ZnO has a wurtzite-type hexagonal crystal structure and possesses a wide band gap energy of approximately 3.4 eV at room temperature, along with high physical and chemical stability.^{11 -17 -17} Nonetheless, there are several limitations to the exploitation of the ZnO-based sensing material as a gas sensor, including poor selectivity and high power consumption due to the high operating temperature $(>200\text{ °C})$.¹⁸ Moreover, the need for a heater alertly carries the risk of fire ignition of flammable liquids or gases in the monitoring environment.

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Notably, the variable thermal load (constantly changing heating and cooling processes) can induce rapid changes in the performance and shorten the durability of the ZnO gas sensor, followed by the disruption of the sensor material and electrical contacts between the metal and $ZnO.¹⁹$ $ZnO.¹⁹$ $ZnO.¹⁹$ Nevertheless, through the optimization of morphology, structure, dopant type, and amount within the fabrication method of ZnO nanomaterials, these drawbacks can be minimized signifi-cantly.^{[20](#page-10-0)}

A large spectrum of nanostructures, such as nanofilms, nanorods, nanoflowers, and nanowires, for MOS-based sensors, can be effectively synthesized by hydrothermal, solvothermal, electrospinning, and DC or radio frequency (RF) magnetron sputtering techniques.^{21,[22](#page-10-0)} A highly ordered nanostructure (i.e., ZnO) is particularly advantageous, as it provides a larger surface area for gas adsorption and enables efficient molecular diffusion of the target gas. In order to achieve the desired characteristics, magnetron sputtering of the sensor material is particularly favorable. This method provides a reliable and nontoxic approach for the fabrication of ZnO nanorods in a vacuum environment with high purity, controllable surface morphology, and thickness.[23](#page-10-0),[24](#page-10-0) The critical parameters are the vacuum level in the magnetron chamber, substrate temperature, and applied power, which can further increase (or decrease) the specific surface area of the ZnO thin film.^{[25](#page-10-0)} Furthermore, using the magnetron sputtering method at different conditions, namely codeposition (uses two or more targets) or single deposition (uses one target), it is possible to incorporate different doping elements into the main working sensitive material (ZnO). For instance, the addition of cobalt results in tuning of the band gap energy and electrical properties of ZnO at a low dopant content, thereby improving its gas-sensing response. The catalytic activity and oxidation of cobalt oxide in the presence of gases like acetone, benzene, ethanol, hydrogen gas (H_2) , and carbon dioxide (CO_2) at low temperatures further elevates the response of cobalt-doped ZnO nanostructures.

The fabrication of CZO nanostructures by magnetron sputtering at room temperature (RT) provides a reliable environment for obtaining nanorods with a high surface area and uniform nanostructures.^{[26,27](#page-10-0)} Also, transition metal (TM) doping (Al, Ti, In, and Ni) into ZnO has been found to enhance the response and selectivity of the nanofilms toward specific gases, such as CO_x , H_2 , and H_2S . For example, Li et al. synthesized CZO nanofilms by cosputtering and demonstrated their potential as CO_x sensors with high sensitivity at 350 $^{\circ}$ C.²⁸ There are only a few works on the application of CZO nanofilms for $CO₂$ gas sensing near RT. In addition, a literature survey of $CO₂$ sensors is presented in Table 1 and the Supporting Information (see [Table](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) S1).

The main focus of this work is the fabrication of novel $CO₂$ gas-sensitive CZO nanorods with improved morphological and electrical properties by the RF magnetron sputtering method. The morphological and structural properties of the sputtered thin films were characterized using scanning electron microscopy (SEM), X-ray diffraction analysis (XRD), atomic force microscopy (AFM), photoluminescence spectroscopy (PL), Fourier-transform infrared spectroscopy (FTIR), and UV−vis spectroscopy. The CZO-based gas sensors were prepared by direct deposition of thin films on integrated gold microelectrodes on glass substrates. The gas-sensing performance of the obtained device was studied at various $CO₂$ gas concentrations (1−1500 ppm) at RT. The gas response properties showed that the fabricated sensor exhibited a high gas response and more selective and relatively stable features for $CO₂$ gas at RT.

EXPERIMENTAL SECTION

Target Preparation for RF Magnetron Sputtering. The ammonium cobalt(II) sulfate hexahydrate salt was treated thermally (300 °C for 6 h) to obtain cobalt oxide $(Co₃O₄)$ powder. Zinc oxide (ZnO) and $Co₃O₄$ powders were mixed in an ethanol medium and homogenized in a grinding chamber for 12 h at 400 rpm for better distribution of the precursor materials. The wet material was then dried in an oven at 60 °C for 48 h and granulated through a sieve of 0.9 mm. The granules were further treated thermally at 400 $^{\circ}$ C for 4 h with subsequent sieving at similar conditions. After that, to achieve complete crystallization, the material was sintered at 800 °C for 4 h.

Figure 1. Schematic illustration of the preparation of the CZO target (Step 1) and the deposition of CZO thin films by RF magnetron sputtering (Step 2).

Table 2. Magnetron Sputtering Deposition Parameters of ZnO and CZO Thin Films

sample name	target name	RF power (W)	tooling factor $(\%)$	deposition rate (nm/s)	average thickness (nm)
ZnO	pure ZnO	45	95	0.032 ± 0.011	85.64 ± 0.12
CZO-45W	Co-doped ZnO	45	12.5	0.045 ± 0.004	97.55 ± 0.11
CZO-60W	Co-doped ZnO	60	110.3	0.057 ± 0.003	110.07 ± 0.14
CZO-75W	Co-doped ZnO	75	109.8	0.118 ± 0.005	111.67 ± 0.09

The powders were pressed into a pellet disc with a diameter of \varnothing = 60 mm and a height of 3 mm by applying a pressure of 15 MPa. Additional sintering at 1100 °C for 6 h at a heating rate of 3 °C per minute allowed the pressed discs to be transformed into solid ceramic bodies. Finally, a solid CZO target was obtained for deposition by RF magnetron sputtering. Schematic illustration of the preparation of the CZO target and the deposition of CZO thin films by RF magnetron sputtering are shown in Figure 1.

The CZO sensor devices were manufactured on silicon dioxide (SiO₂)-coated glass with a Cr layer and gold (Au) electrode. A selfmade target for magnetron sputtering was prepared, as shown in Figure 1 (Step 1). The Cr layer acts as a diffusion barrier where the top electrode layer is prevented from diffusing into the substrate, allowing a low-resistance contact to be made with the material. The Cr layer also helps improve the adhesion between the substrate and the top electrode layer, which is important for the long-term stability

and performance of the device. The IDT contacts were manufactured by Au sputtering with a thickness of 40 nm over the CZO layer using an aluminum mask, as shown in Figure 1 (Step 2).

Preparation of CZO Thin Films. CZO thin films were deposited on glass substrates without additional heating using the RF magnetron sputtering technique.^{[39](#page-11-0)} The substrates were ultrasonically cleaned in ethanol and acetone, rinsed in deionized water, and air-dried before deposition. For the sputtering deposition, the working chamber was vacuumed to reach a base pressure of 3×10^{-7} mbar. The substrates were fixed at a distance of 6 cm from the CZO target surface. The CZO thin films were deposited with a mixture of reactive gases (pure argon (Ar) and oxygen (O_2) , 5:1) inside the chamber. The gas purities were 99.9996% for Ar and 99.9995% for O_2 . Presputtering was carried out for 40 min to clean and equilibrate the target surface prior to deposition. The same conditions were used for sputtering and sputtering, except for the deposition rate. During the deposition of

Figure 3. SEM images of the CZO thin films deposited at different RF powers: (a) 45, (b) 60, and (c) 75 W. (d) Cross sections of CZO thin films.

CZO films, the total pressure was maintained at 5 mTorr, with a gas flow of 20 sccm. The input powers at the target were 45, 60, and 75 W. The deposition rates and durations used for the production of CZO thin films are shown in [Table](#page-1-0) 1. The deposition rates varied from 0.013 to 0.068 nm/s with RF power. Full details of the preparation procedure for the CZO gas sensor device with Au IDT electrodes are provided in [Table](#page-2-0) 2.

Characterization of CZO Films. The phase composition and crystal structure of all thin films were carefully examined using XRD (SmartLab Rigaku; Cu K α_1 was used as a radiation source, λ = 0.15406 nm, tube voltage, and tube current were 30 kV and 25 mA, respectively, scanning speed was 0.02°/s, scanning range was 20− 80°). The surface morphology of the CZO thin films was studied via SEM (ZEISS Crossbeam 540). The chemical components were inspected by X-ray photoelectron spectroscopy (XPS) (NEXSA, Thermo Scientific) and energy dispersive spectroscopy (EDS) (JSM-IT200). AFM (SmartSPM 1000) analysis was performed to investigate the roughness distribution of nanoparticles. The thicknesses of the CZO nanofilms were quantified by a stylus profilometer (Dektak XT Stylus Profiler). The Hall effect analysis of the thin films was performed via an HMS-5500 equipment system with a constant magnetic field of 0.55 T. Optical properties of the CZO thin films were determined by UV−vis spectrophotometer (Evolution 300 UV−vis) within the wavelength range of 200−1000 nm. Measurements of the gas response of the sensors were provided by the gas measurement unit "GMS-311". The gas measurements of the gas sensors were done at room temperature (RT \sim 27 °C) for different CO₂ gas concentrations (1-1500 ppm). The best working gas concentration for the fabricated gas sensors was then specified. Some gas-sensing measurement parameters, such as gas response, selectivity, and stability, were investigated for a full understanding of the quality of the produced gas sensors. The gas response of the CZO sensors was estimated using the relation $S = R_{air}/R_{gas}$. The gas-sensing measurements of the fabricated sensors for $CO₂$ and different gases were carried out by using a computer-controlled device. The setup consists of a current−voltage source measurement unit (Keithley-2450), a temperature controller (SRS Stanford Research Systems − CTC100), gas flow controllers (MFC-1 and MFC-2), a humidity sensor, a test chamber, a digital interface unit, gas cylinders (dry air and target gas $CO₂$), and a PC. A clear, detailed schematic of the

Figure 4. AFM images (2D and 3D) of the CZO thin films grown by RF sputtering at various RF powers: (a) 45, (b) 60, and (c) 75 W.

Figure 5. (a) FTIR spectra, (b) PL, and (c) Hall measurement results of ZnO and CZO thin films.

sensing setup and gas measurements is provided in the Supporting Information (see [Figure](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) S1).

■ **RESULTS AND DISCUSSION**

Microstructural and Morphological Characterization of the Produced Thin Films. The influence of increasing RF sputtering power on the structures of the ZnO and CZO (CZO-45W, CZO-60W, CZO-75W) thin films was determined by XRD. As evident in [Figure](#page-3-0) 2a, CZO thin films reveal

a strong preferential orientation toward the (002) plane of polycrystalline hexagonal ZnO with minor changes in the characteristic parameters reported in [Table](#page-3-0) 3. The peak intensity of the CZO thin films increased, along with a shift in the peak positions from 34.39 to 34.37°, reaching 34.41° at 45, 60, and 75 W, respectively. All the peak angles are in good agreement with the *c*-axis-oriented ZnO (002) peak from JCPDS card No. 00−001−1136 at 34.4°. CZO-60 W displayed an expansion in volume and lattice parameters as well as a

Figure 6. Illustration of the effect of the deposition rate on the formation of CZO thin films.

uniform strain throughout the crystal lattice, as shown in [Figure](#page-3-0) $2b⁴⁰$ $2b⁴⁰$ $2b⁴⁰$ The trends of shrinking full width at halfmaximum (fwhm) and the growing crystallite size in [Table](#page-3-0) 3 are similar to the results reported by Gonçalves et al.²⁵ at RF powers of 50 and 75 W.

The changes in the surface morphology and topography of the CZO thin films due to the increase in the power of magnetron sputtering were analyzed using SEM and AFM. From [Figure](#page-3-0) 3a−c, it can be seen that the shape of the particles sputtered at 45W is close to a sloped cylinder, while at higher powers of sputtering, 60 and 75 W, the thin films are composed of more vertically inclined rod-like particles with a defined hexagonal shape observed from the top view. Although the films were sputtered uniformly, a visible increase in the particle densities of CZO-60W and CZO-75W thin films was observed. [Figure](#page-3-0) 3d demonstrates the changes in particle heights as they increase due to the higher energy of sputtering in accordance with [Table](#page-2-0) 2.

The AFM micrographs taken for 2.5 *μ*m × 2.5 *μ*m area and shown in [Figure](#page-4-0) 4a−c allow access to the difference qualitatively and quantitatively regarding the surface topography of CZO thin films that appear to be nucleated as individual, conical islands. It is widely known that optimal surface roughness should be achieved to attain proper gas sensing, as an increase in this parameter generally leads to an increase in the number of adsorption sites for oxygen molecules[.41,42](#page-11-0) The root-mean-square (RMS) value of 7.5 nm for CZO-60 W was found to be higher than that of CZO-45W and CZO-75W thin films, 6.4 and 7.1 nm, respectively. Quite possibly, the deposition power of 60 W results in the highest total surface area of the prepared material due to the intermediate grain size and highest RMS value.^{[43](#page-11-0)} These results suggest that the morphology and topography of the CZO thin films were significantly affected by the power applied to the RF source as the main deposition condition.

Optical and Electrical Properties of CZO Thin Films. The FTIR spectra of the fabricated ZnO and CZO films, such as CZO-45W, CZO-60W, and CZO-75W sensors, are shown in [Figure](#page-4-0) 5a. The FTIR results were performed for the CZO thin films using the KBr pellet method in the wavenumber range of 500−3000 cm[−]¹ . All of the CZO thin films exhibited absorption bands at 2349, 1989, 955, 817, and 581 cm[−]¹ . The absorption bands at 581 and 817 cm^{-1} are attributed to the Zn–O stretching in the ZnO lattice.^{[44](#page-11-0)} The absorption peaks

observed at 2349 and 1989 cm[−]¹ are related to the existence of $CO₂$ molecules in air.^{[45](#page-11-0)} The medium to weak band at 955 cm[−]¹ is assigned to the metal−oxygen vibration frequency due to the changes in the microstructural features (see the XRD results and [Table](#page-3-0) 3) by the increase of the amount of cobalt (CZO-45W, CZO-60W, and CZO-75W) in the Zn−O lattice. In addition, the band gap energies of the CZO thin films were calculated by UV−vis spectroscopy and are provided in the Supporting Information (see [Figure](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) S2). A detailed investigation of the existence of the structural defects in the CZO thin film was carried out by PL. [Figure](#page-4-0) 5b shows the PL spectra of the pure ZnO and CZO samples at room temperature in the 400−700 nm wavelength range. In the case of ZnO, the near band emission of crystal defects is typically observed in the UV region (<400 nm) with a sharp peak, while the deep level emission (DLE) is usually observed in the visible light area $($ >400 nm) with a broad peak.^{[46](#page-11-0)} In accordance with many theoretical and experimental PL results, it can be assumed that the visible emissions are related to the substitution of oxygen atom to zinc atom position represented by a variety of intrinsic abnormalities, such as oxygen vacancies (V_O) , interstitial oxygen (O_i) , antisite oxygen (O_a) , and zinc vacancies (V_{Zn}) , among others.^{[47](#page-11-0)} In the visible light region, the ZnO and CZO thin films exhibit similar line shapes with one PL peak at 500 nm, as seen in [Figure](#page-4-0) 5b. These results are in line with the literature, 48 which is explained by the recombination of electrons and twice-ionized oxygen vacancies (V_O) with photogenerated holes in the ZnO lattice.⁴⁹ Broad blue emission at 484 nm bands is typically attributed to the radiative recombination of oxygen vacancies and electrons.⁵⁰ It has been found that the intensity of the DLE of CZO samples decreases noticeably with increasing RF sputtering power. In the case of CZO-75W, the PL intensity is observed to be slightly lower than those of the CZO-45W and CZO-60W samples, which may be ascribed to the increase in V_O , O_i , or Zni defects.

Hall effect studies were carried out to obtain the Hall parameters, such as resistivity (ρ) , Hall mobility (μ) , and carrier concentration (*n*) by HMS-5500. According to the Hall measurement results, the carrier concentration of the ZnO increased when Co atoms were introduced, and the maximum value corresponded to CZO-60W $(n = 1.3 \times 10^{20} \text{ 1/cm}^3)$. This value is smaller for the sample CZO-75W, which was

Figure 7. (a) Resistance changes and (b) responses of CZO-45W, CZO-60W, and CZO-75W sensors to CO₂ at gas concentrations of 1–1500 ppm.

sputtered under the same conditions, except for the applied magnetron power of 75 W. In a comparable way, as evidenced by the same graph, the electrical resistivity of CZO-60W has shown the lowest value of around 0.08 Ω ·cm and increases for CZO-75W. As is known, the resistance and conductivity properties of CZO thin films obtained using magnetron sputtering strongly depend on the parameters of the magnetron sputtering system (i.e., depends on power and deposition rate). It is very important to obtain a homogeneous film by the sequential application of layers. In this work, thin films of ZnO and CZO were obtained by using magnetron sputtering by varying the device power to 45, 60, and 75 W, respectively. However, at a 75 W power, electrical properties such as carrier concentration, resistivity, and mobility deteriorate sharply, as shown in [Figure](#page-4-0) 5c. This may be due to an increase in the deposition rate. As shown in [Table](#page-2-0) 2, the deposition rate at 75 W increases sharply (almost 2 times) compared with that at 45 and 60 W. Rapid deposition can limit the time required for grain growth, which in turn will affect the microstructure, crystallinity and uniformity of the dopant distribution of ZnO/ CZO. Moreover, the surface smoothness and porosity of the thin films are important parameters that are maintained by the deposition rate. [Figure](#page-5-0) 6 clearly shows examples of the formation of CZO thin films at various deposition powers, such as 45, 60, and 75 W. The slow deposition rate (45W) promotes the formation of compact grains with smooth surfaces and reduces defects in the structure. Under such conditions, the particles have enough time to organize into compact structures, ensuring a high degree of adhesion and surface uniformity. As the deposition rate increases (60 and 75 W), a reduction in grain size is observed as the nuclei do not have time to fully form. This effect is accompanied by an increase in the porosity and various types of defects in the film. In the context of gas sensors, the formation of defects can lead to an increase in the number of vacant sites for oxygen, which in turn increases the gas response of the sensing material (CZO thin films). Thus, setting up the experiment makes it possible to determine the optimal limit of proper control for producing CZO thin films by RF magnetron sputtering.

In addition, the inhibitory effect of such doping on the production of O_2 -derived defects at the ZnO grain boundary surfaces is the possible reason for the decrease of resistivity that occurred after the introduction of Co dopant into the

ZnO matrix.[51](#page-11-0) For CZO-75W, the observed decrease in the *n* carriers can be accounted for by the Zn vacancies (V_{Zn}) , which can induce the acceptor level, while oxygen vacancies behave as deep donors and Zn as shallow donors.^{[52](#page-11-0)}

Gas-Sensing Properties of the CZO Sensors. Figure 7 depicts the resistance-time change reaction of the CZO sensors when exposed to $CO₂$ gas ranging from 1 to 1500 ppm at room temperature under dry air. As shown in Figure 7a, the gas sensor exhibits a nonlinear change in the concentration versus gas response. This pattern is consistent with the observations reported in various studies.^{53–[55](#page-11-0)} These studies emphasized nonlinear trends extending beyond certain concentrations according to the $S \sim C^n$ dependence. In this study, the gas response exhibits a consistent linear relationship within the 1− 300 ppm range. However, as the concentration increases, a discernible shift toward nonlinear behavior becomes increasingly evident. Furthermore, the enhanced performance of the CZO-60W sensor is unmistakably apparent when compared to its CZO-45W and CZO-75W counterparts. Specifically, CZO-60W demonstrates superior gas response at room temperature in the presence of dry air. It demonstrates a heightened response at various concentration levels: 1, 50, 100, 150, 250, 500, 750, 1000, 1250, and 1500 ppm, with corresponding response values of 1.2, 1.29, 1.32, 1.37, 1.41, 1.45, 1.51, 1.54, 1.55, and 1.56, respectively. The variance observed in the gas responses of these sensors can be attributed to the distinct morphology of the sensing surface pertinent to each sensor type. The introduction of Co doping leads to an increased occurrence of point defects and oxygen vacancies within the CZO sensors.^{[56](#page-11-0)} This augmentation contributes to the enhanced gas response in contrast to undoped ZnO sensors. The relationship between the $CO₂$ gas concentration and the corresponding sensor response was deduced, as depicted in Figure 7b.

Additionally, the gas-sensing capabilities of the developed gas-sensing materials (CZO thin films) were tested at RT under various relative humidity (RH) conditions. The impact of RH on gas sensitivity was examined at 25, 50, and 75% RH, respectively, utilizing a humidity controller with an accuracy of $\pm 0.1\%$ RH, which was integrated into the gas measurement system. Humidity tests revealed that the resistance of the sensors decreases with humidity in dry air from ∼3.8 to ∼3.3 Ω at 50% RH for CZO-60W. This phenomenon was also

Figure 8. (a) Stability and (b) selectivity results of the fabricated CZO sensors for 500 ppm of different target gases at RT; cross-selectivity measurements of the CZO-60W sensor (c) with CO and CH₄ and (d) a mixture of CO₂ and acetone.

detected for the other CZO-45W and CZO-75W sensors (see [Figure](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) S3, Supporting Information). The decrease in the gas response is a result of increased electron concentration within the sensing material, which is attributed to the absorption of water molecules on the surface of the sensing material.

We evaluated the stability performance of the CZO-based sensors (CZO-45W, CZO-60W, and CZO-75W) by exposing them to 500 ppm $CO₂$ gas for one month, as shown in Figure 8a. Among these devices, the CZO-60W gas sensor exhibited a remarkably stable response $(R_a/R_g = 1.45)$, which subsequently decreased to an acceptable value $(R_a/R_g = 1.39)$ for the gas response. The sensor's stability decreased due to the adsorption of moisture from air. Interestingly, the gas response of the CZO-60W sensor increased at the optimal ratio (∼1.8) of Co/Zn (see [Table](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) S2, ICP results, Supporting Information). Indeed, when $CO₂$ gas molecules are present in the gas chamber, they can be adsorbed on the surface of the gas sensor and occupy the adsorption sites. Therefore, the number of adsorption sites and surface defects increased (see the PL results), leading to higher adsorption reactions of $CO₂$ gas molecules and resulting in a high gas response of the CZO gas sensors. Finally, we examined the selectivity and crosssensitivity of the CZO gas sensors by exposing them to 500 ppm CO, CO_2 , CH_4 , N₂O, NO₂, H₂, acetone, and ethanol. Figure 8b presents the gas selectivity pattern of the CZO gas sensor in response to the aforementioned gases. The corresponding $CO₂$ gas responses were evaluated for CZO-45W, CZO-60W, and CZO-75W, respectively.

Cross-sensitivity studies are pivotal in gas sensor development to ensure improved specificity and accuracy. By investigating how sensors respond to various gases, these studies contribute to enhanced selectivity, reliability, and overall performance, which are crucial for gas sensor applications.^{[57](#page-11-0)} In our work, the developed CZO-based sensing materials have demonstrated high selectivity properties upon consecutive exposure $(CO_2, CO,$ and $CH₄)$ and when exposed to a mixture of $CO₂$ and acetone (see Figure 8c,d). It was observed that certain gases influenced the resistance background level, potentially indicating low desorption. However, this effect is reversible after exposure to other gas types, such as methane, in our tests. The sensing material was stable in the presence of a mixture of $CO₂$ and acetone (500 + 50 ppm), with the response value changing by 5% (R_a/R_g) shifting from 1.50 to 1.43). Notably, the background value remains consistent before and after the exposure to the gas mixture. The high selectivity can potentially be explained through ab initio calculations of the adsorption energy. Thus, the CZO-60W sensor showed excellent selectivity for CO, $CO₂$, and $CH₄$ gases.

Gas-Sensing Mechanism. The gas-sensing mechanism in MOS-based sensing materials is often explained by the surface conductivity theory.^{[58](#page-11-0)} According to this theory, the interaction between the metal oxide surface and gas molecules induces changes in material conductivity, serving as a sensitive indicator of gas presence and concentration. This phenomenon is rooted in the adsorption and desorption processes with factors such as chemisorption, physisorption, defects, grain

Figure 9. Schematic illustration of the CZO gas sensor with $CO₂$ target gas: reaction mechanism and energy level of the CZO gas sensor (a) before and (b) after exposure to CO_2 gas; (c) schematic diagram of the corresponding energy band structure of CZO; and (d) physisorption-based gassensing mechanism with a shift in the work function under exposure to different gases.

Table 4. Summary of the Recently Reported CZO Gas Sensors

boundaries, and surface morphology, which contribute to the overall gas-sensing performance of CZO. Understanding these complex interactions is crucial for optimizing the design and efficacy of CZO-based gas sensors. The resistivity of the sensors depends on the concentration of oxygen vacancies, which occur by the doping of $Co³⁺$ into the ZnO lattice, as shown in Figure 9a−c. Oxygen atoms react with the positive oxygen vacancies to form oxygen ions at their lattice sites.

$$
V''_0 + 2e (CB) + \frac{1}{2}O_2 (gas) \leftrightarrow O^x_O
$$
 (1)

This reaction reduces the conductivity of the sensor, as ZnO loses electrons in the presence of an oxygen environment.

The CO_2 gas reacts with O_O^x to form metastable carbon tetroxide (CO_3) .^{[59](#page-11-0)}

$$
CO2 (ads) + O0x \leftrightarrow CO3 (gas) + V0x(2)
$$
 (2)

 $CO₃$ has a short lifetime; thus, it further dissociates into $CO₂$ and O_2 .

The neutral oxygen vacancies ionize to give electrons back to the conduction band:

$$
V_O^x \leftrightarrow V_O^{**} + 2e^- \tag{3}
$$

Thus, the adsorption of $CO₂$ gas onto ZnO increases the free carrier concentration and the conductivity increases upon exposure to $CO₂$ gas. An additional physisorption mechanism is illustrated in Figure 9d. Physisorption does not result in electronic structures or electron transitions, as no chemical bonds occur. However, there is a uniform upward shift in the work function of the sensing layer, ranging from Φ_{S1} to Φ_{S2} by a specific value. 60 It is noteworthy that within this investigation, two observed phenomena substantiate the binary nature of the sensory properties: physisorption and chemisorption, as confirmed by experimental data (see [Figure](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) S4, Supporting Information).

Notably, with a medium vacuum level (5 mTorr) and optimal power of the magnetron source (60 W), we achieved a huge enhancement of the gas response for the CZO-based sensor compared to ZnO (as a control sample) at a $CO₂$ concentration of 500 ppm at RT. This can be explained by the variation in the morphological and electrical phenomena on the CZO sensor's surface. Moreover, the addition of Co

dopant into the ZnO nanostructure contributes to the formation of oxygen vacancies (see [Figure](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) S5, Table S3– XPS results, and Figure S6-[SEM/EDX](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf) results in the Supporting Information), which can increase the carrier density and accelerate the electron transfer during the $CO₂$ gas reaction. This work presents a reliable CO_2 -sensing material that has a high sensing response at RT and expands on the effect of sputtering power through a variety of characterization methods. Similar to this work, Mani et al. reported a CZO nanostructure that is very sensitive at room temperature, albeit for acetaldehyde gas. 61 Increasing interest in the doping of ZnO by the cobalt element can be explained due to its large solubility in the ZnO matrix and an ionic radius (0.58 Å) similar to that of Zn (0.60 Å), which makes it a promising candidate for doping among TMs.^{62} TMs.^{62} TMs.^{62} A list of recently reported CZO-based gas sensors is listed in [Table](#page-8-0) 4. This study's CZO gas sensor study exhibits several favorable characteristics when compared to similar CZO sensors, including a relatively low operating temperature (RT), minimal doping content (1.81 atom %), and a quick response time (72 s).

■ **CONCLUSIONS**

In conclusion, CZO thin films (CZO-45W, CZO-60W, and CZO-75W) were successfully fabricated on glass substrates by the RF magnetron technique using a cost-effective and selfmade target. The XRD results revealed that all thin films were polycrystalline with a hexagonal wurtzite crystal structure (ZnO) with a preferential orientation toward the (002) plane. All of the peak angles are in good agreement with the *c*-axisoriented ZnO (002) peak from JCPDS card No. 00−001− 1136 at 34.4°. According to the AFM outputs, an RMS value of 7.5 nm for CZO-60W was found to be higher than that of the CZO-45W and CZO-75W thin films, 6.4 and 7.1 nm, respectively. XPS measurements demonstrated the presence of oxygen vacancies (V_O) in the CZO thin films, where CZO-60W had a higher intensity than the CZO-45W and CZO-75W samples. The gas-sensing properties of sensors made from CZO nanostructures were examined across a range of $CO₂$ concentrations from 1 to 1500 ppm. The gas responses and response/ recovery times of the sensors were assessed at different $CO₂$ levels. The CZO-45W sensor exhibited a low response **f** $\left(\frac{R_{\rm a}}{R_{\rm g}} = 0.36\right)$ $\frac{a}{s}$ = 0.36 with a response time of 77 s. Meanwhile,

the CZO-60W sensor displayed an even higher response

i $\overline{}$ $\left(\frac{R_a}{R_g} = 1.45\right)$ and a faster response time of 72 s. The superior *R* a g

performance of the CZO-60W sensor can be attributed to its greater capacity for $CO₂$ molecule adsorption within its structure, owing to its higher RMS and the presence of defects (V_O) . Additionally, both sensors exhibited a linear increase (up to 300 ppm) in gas response with an increasing $CO₂$ gas concentration. These findings underscore the potential of CZO-based sensors for $CO₂$ gas detection applications and offer a promising path for the investigation and development of low-cost and energy-efficient advanced $CO₂$ sensors.

■ **ASSOCIATED CONTENT**

\bullet Supporting Information

The Supporting Information is available free of charge at [https://pubs.acs.org/doi/10.1021/acssensors.3c02059](https://pubs.acs.org/doi/10.1021/acssensors.3c02059?goto=supporting-info).

 $CO₂$ sensing reports with surface morphology and selectivity comparison along with other essential parameters; schematic illustration of the gas-sensing measurement system; UV−vis absorption spectra of CZO-45W, CZO-60 W, and CZO-75 W thin films; the resistance changes of the CZO sensors at different humidity conditions; the resistance changes of the CZO-60W sensor in air and Ar environments; ICP results of the CZO samples; XPS O 1s scan of the CZO thin films; oxygen states of the CZO samples by XPS, and SEM/ EDX images of the CZO thin films ([PDF\)](https://pubs.acs.org/doi/suppl/10.1021/acssensors.3c02059/suppl_file/se3c02059_si_001.pdf)

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Author Contributions

The manuscript was written and edited with contributions from all authors. Y.R. and A.N. conducted the fabrication of CZO thin films. G.Y. and A.T. performed and analyzed all gassensing experiments. B.S. and A.M. were involved in planning, discussions, editing, and manuscript supervision. All authors have approved the final version of the manuscript.

Notes

The authors declare no competing financial interest.

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